NSN 5961-01-040-0939

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-040-0939 **Inclosure Material:** Glass and metal **Overall Length:** 8.5 millimeters **Overall Diameter:** 3.0 millimeters **Mounting Method: Terminal Features Provided:** Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 35.0 reverse voltage, instantaneous **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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